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Understanding <u>Embedded - FPGAs (Field Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	72
Number of Logic Elements/Cells	576
Total RAM Bits	6144
Number of I/O	59
Number of Gates	31000
Voltage - Supply	4.75V ~ 5.25V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 70°C (TA)
Package / Case	84-LCC (J-Lead)
Supplier Device Package	84-PLCC (29.31x29.31)
Purchase URL	https://www.e-xfl.com/product-detail/intel/epf10k10lc84-4n

Email: info@E-XFL.COM

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Figure 1 shows a block diagram of the FLEX 10KE architecture. Each group of LEs is combined into an LAB; groups of LABs are arranged into rows and columns. Each row also contains a single EAB. The LABs and EABs are interconnected by the FastTrack Interconnect routing structure. IOEs are located at the end of each row and column of the FastTrack Interconnect routing structure.

Embedded Array Block (EAB) I/O Element IOE IOE IOE IOE IOE IOE IOE IOE IOE (IOE) IOE Column Logic Array Interconnect EAB Logic Array Block (LAB) IOE Logic Element (LE) Row EAB Interconnect Local Interconnect Logic Array

Figure 1. FLEX 10KE Device Block Diagram

IOE

IOE

IOE

IOE

IOE

IOE

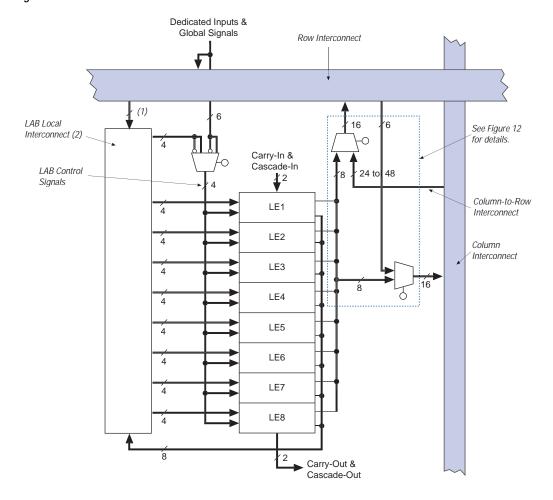
Embedded Array

FLEX 10KE devices provide six dedicated inputs that drive the flipflops' control inputs and ensure the efficient distribution of high-speed, low-skew (less than 1.5 ns) control signals. These signals use dedicated routing channels that provide shorter delays and lower skews than the FastTrack Interconnect routing structure. Four of the dedicated inputs drive four global signals. These four global signals can also be driven by internal logic, providing an ideal solution for a clock divider or an internally generated asynchronous clear signal that clears many registers in the device.

IOE

IOE

Figure 7. FLEX 10KE LAB



Notes:

- (1) EPF10K30E, EPF10K50E, and EPF10K50S devices have 22 inputs to the LAB local interconnect channel from the row; EPF10K100E, EPF10K130E, EPF10K200E, and EPF10K200S devices have 26.
- (2) EPF10K30E, EPF10K50E, and EPF10K50S devices have 30 LAB local interconnect channels; EPF10K100E, EPF10K130E, EPF10K200E, and EPF10K200S devices have 34.

The programmable flipflop in the LE can be configured for D, T, JK, or SR operation. The clock, clear, and preset control signals on the flipflop can be driven by global signals, general-purpose I/O pins, or any internal logic. For combinatorial functions, the flipflop is bypassed and the output of the LUT drives the output of the LE.

The LE has two outputs that drive the interconnect: one drives the local interconnect and the other drives either the row or column FastTrack Interconnect routing structure. The two outputs can be controlled independently. For example, the LUT can drive one output while the register drives the other output. This feature, called register packing, can improve LE utilization because the register and the LUT can be used for unrelated functions.

The FLEX 10KE architecture provides two types of dedicated high-speed data paths that connect adjacent LEs without using local interconnect paths: carry chains and cascade chains. The carry chain supports high-speed counters and adders and the cascade chain implements wide-input functions with minimum delay. Carry and cascade chains connect all LEs in a LAB as well as all LABs in the same row. Intensive use of carry and cascade chains can reduce routing flexibility. Therefore, the use of these chains should be limited to speed-critical portions of a design.

Carry Chain

The carry chain provides a very fast (as low as 0.2 ns) carry-forward function between LEs. The carry-in signal from a lower-order bit drives forward into the higher-order bit via the carry chain, and feeds into both the LUT and the next portion of the carry chain. This feature allows the FLEX 10KE architecture to implement high-speed counters, adders, and comparators of arbitrary width efficiently. Carry chain logic can be created automatically by the Altera Compiler during design processing, or manually by the designer during design entry. Parameterized functions such as LPM and DesignWare functions automatically take advantage of carry chains.

Carry chains longer than eight LEs are automatically implemented by linking LABs together. For enhanced fitting, a long carry chain skips alternate LABs in a row. A carry chain longer than one LAB skips either from even-numbered LAB to even-numbered LAB, or from odd-numbered LAB to odd-numbered LAB. For example, the last LE of the first LAB in a row carries to the first LE of the third LAB in the row. The carry chain does not cross the EAB at the middle of the row. For instance, in the EPF10K50E device, the carry chain stops at the eighteenth LAB and a new one begins at the nineteenth LAB.

Figure 9 shows how an n-bit full adder can be implemented in n+1 LEs with the carry chain. One portion of the LUT generates the sum of two bits using the input signals and the carry-in signal; the sum is routed to the output of the LE. The register can be bypassed for simple adders or used for an accumulator function. Another portion of the LUT and the carry chain logic generates the carry-out signal, which is routed directly to the carry-in signal of the next-higher-order bit. The final carry-out signal is routed to an LE, where it can be used as a general-purpose signal.

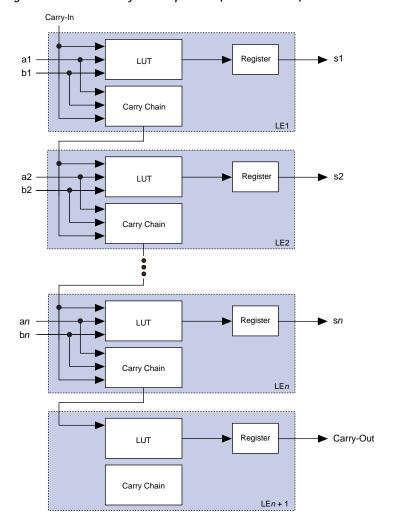


Figure 9. FLEX 10KE Carry Chain Operation (n-Bit Full Adder)

Normal Mode

The normal mode is suitable for general logic applications and wide decoding functions that can take advantage of a cascade chain. In normal mode, four data inputs from the LAB local interconnect and the carry-in are inputs to a four-input LUT. The Altera Compiler automatically selects the carry-in or the DATA3 signal as one of the inputs to the LUT. The LUT output can be combined with the cascade-in signal to form a cascade chain through the cascade-out signal. Either the register or the LUT can be used to drive both the local interconnect and the FastTrack Interconnect routing structure at the same time.

The LUT and the register in the LE can be used independently (register packing). To support register packing, the LE has two outputs; one drives the local interconnect, and the other drives the FastTrack Interconnect routing structure. The DATA4 signal can drive the register directly, allowing the LUT to compute a function that is independent of the registered signal; a three-input function can be computed in the LUT, and a fourth independent signal can be registered. Alternatively, a four-input function can be generated, and one of the inputs to this function can be used to drive the register. The register in a packed LE can still use the clock enable, clear, and preset signals in the LE. In a packed LE, the register can drive the FastTrack Interconnect routing structure while the LUT drives the local interconnect, or vice versa.

Arithmetic Mode

The arithmetic mode offers 2 three-input LUTs that are ideal for implementing adders, accumulators, and comparators. One LUT computes a three-input function; the other generates a carry output. As shown in Figure 11 on page 22, the first LUT uses the carry-in signal and two data inputs from the LAB local interconnect to generate a combinatorial or registered output. For example, in an adder, this output is the sum of three signals: a, b, and carry-in. The second LUT uses the same three signals to generate a carry-out signal, thereby creating a carry chain. The arithmetic mode also supports simultaneous use of the cascade chain.

Up/Down Counter Mode

The up/down counter mode offers counter enable, clock enable, synchronous up/down control, and data loading options. These control signals are generated by the data inputs from the LAB local interconnect, the carry-in signal, and output feedback from the programmable register. Use 2 three-input LUTs: one generates the counter data, and the other generates the fast carry bit. A 2-to-1 multiplexer provides synchronous loading. Data can also be loaded asynchronously with the clear and preset register control signals without using the LUT resources.

For improved routing, the row interconnect consists of a combination of full-length and half-length channels. The full-length channels connect to all LABs in a row; the half-length channels connect to the LABs in half of the row. The EAB can be driven by the half-length channels in the left half of the row and by the full-length channels. The EAB drives out to the full-length channels. In addition to providing a predictable, row-wide interconnect, this architecture provides increased routing resources. Two neighboring LABs can be connected using a half-row channel, thereby saving the other half of the channel for the other half of the row.

Table 7 summarizes the FastTrack Interconnect routing structure resources available in each FLEX 10KE device.

Table 7. FLEX 1	Table 7. FLEX 10KE FastTrack Interconnect Resources									
Device	Rows	Channels per Row	Columns	Channels per Column						
EPF10K30E	6	216	36	24						
EPF10K50E EPF10K50S	10	216	36	24						
EPF10K100E	12	312	52	24						
EPF10K130E	16	312	52	32						
EPF10K200E EPF10K200S	24	312	52	48						

In addition to general-purpose I/O pins, FLEX 10KE devices have six dedicated input pins that provide low-skew signal distribution across the device. These six inputs can be used for global clock, clear, preset, and peripheral output enable and clock enable control signals. These signals are available as control signals for all LABs and IOEs in the device. The dedicated inputs can also be used as general-purpose data inputs because they can feed the local interconnect of each LAB in the device.

Figure 14 shows the interconnection of adjacent LABs and EABs, with row, column, and local interconnects, as well as the associated cascade and carry chains. Each LAB is labeled according to its location: a letter represents the row and a number represents the column. For example, LAB B3 is in row B, column 3.

Interconnect Clock Inputs 4 Dedicated Peripheral Inputs Control Bus OE Register 12 D ENA CLRN Chip-Wide Reset Chip-Wide Output Enable OE[7..0] (1) Programmable Delay Output Register (2) D Q CLK[1..0] ENA Open-Drain CLK[3..2] CLRN Output Slew-Rate ENA[5..0] Control VCC CLRN[1..0] Chip-Wide Reset Input Register (2) Б <u>vçc</u> ENA CLRN Chip-Wide Reset

Figure 15. FLEX 10KE Bidirectional I/O Registers

Row and Column 2 Dedicated

Note:

(1) All FLEX 10KE devices (except the EPF10K50E and EPF10K200E devices) have a programmable input delay buffer on the input path.

Row-to-IOE Connections

When an IOE is used as an input signal, it can drive two separate row channels. The signal is accessible by all LEs within that row. When an IOE is used as an output, the signal is driven by a multiplexer that selects a signal from the row channels. Up to eight IOEs connect to each side of each row channel (see Figure 16).

Figure 16. FLEX 10KE Row-to-IOE Connections

The values for m and n are provided in Table 10.

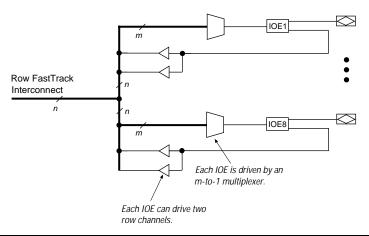


Table 10 lists the FLEX 10KE row-to-IOE interconnect resources.

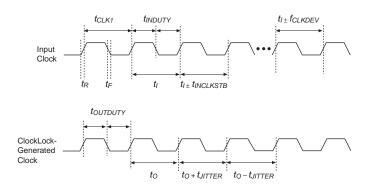
Table 10. FLEX 10Ki	Table 10. FLEX 10KE Row-to-IOE Interconnect Resources									
Device	Channels per Row (n)	Row Channels per Pin (m)								
EPF10K30E	216	27								
EPF10K50E EPF10K50S	216	27								
EPF10K100E	312	39								
EPF10K130E	312	39								
EPF10K200E EPF10K200S	312	39								

ClockLock & ClockBoost Timing Parameters

For the ClockLock and ClockBoost circuitry to function properly, the incoming clock must meet certain requirements. If these specifications are not met, the circuitry may not lock onto the incoming clock, which generates an erroneous clock within the device. The clock generated by the ClockLock and ClockBoost circuitry must also meet certain specifications. If the incoming clock meets these requirements during configuration, the ClockLock and ClockBoost circuitry will lock onto the clock during configuration. The circuit will be ready for use immediately after configuration. Figure 19 shows the incoming and generated clock specifications.

Figure 19. Specifications for Incoming & Generated Clocks

The t_l parameter refers to the nominal input clock period; the t_0 parameter refers to the nominal output clock period.



Tables 12 and 13 summarize the ClockLock and ClockBoost parameters for -1 and -2 speed-grade devices, respectively.

Table 12.	. ClockLock & ClockBoost Param	eters for -1 Speed-C	Grade Device	es		
Symbol	Parameter	Condition	Min	Тур	Max	Unit
t_R	Input rise time				5	ns
t _F	Input fall time				5	ns
t _{INDUTY}	Input duty cycle		40		60	%
f _{CLK1}	Input clock frequency (ClockBoost clock multiplication factor equals 1)		25		180	MHz
f _{CLK2}	Input clock frequency (ClockBoost clock multiplication factor equals 2)		16		90	MHz
f _{CLKDEV}	Input deviation from user specification in the MAX+PLUS II software (1)				25,000 (2)	PPM
t _{INCLKSTB}	Input clock stability (measured between adjacent clocks)				100	ps
t _{LOCK}	Time required for ClockLock or ClockBoost to acquire lock (3)				10	μs
t _{JITTER}	Jitter on ClockLock or ClockBoost-	$t_{INCLKSTB} < 100$			250	ps
	generated clock (4)	$t_{INCLKSTB} < 50$			200 (4)	ps
t _{OUTDUTY}	Duty cycle for ClockLock or ClockBoost-generated clock		40	50	60	%

Symbol	Parameter	Condition	Min	Тур	Max	Unit
t_R	Input rise time				5	ns
t _F	Input fall time				5	ns
t _{INDUTY}	Input duty cycle		40		60	%
f _{CLK1}	Input clock frequency (ClockBoost clock multiplication factor equals 1)		25		75	MHz
f _{CLK2}	Input clock frequency (ClockBoost clock multiplication factor equals 2)		16		37.5	MHz
f _{CLKDEV}	Input deviation from user specification in the MAX+PLUS II software (1)				25,000 (2)	PPM
t _{INCLKSTB}	Input clock stability (measured between adjacent clocks)				100	ps
t _{LOCK}	Time required for ClockLock or ClockBoost to acquire lock (3)				10	μs
t _{JITTER}	Jitter on ClockLock or ClockBoost-	$t_{INCLKSTB} < 100$			250	ps
	generated clock (4)	$t_{INCLKSTB} < 50$			200 (4)	ps
t _{OUTDUTY}	Duty cycle for ClockLock or ClockBoost-generated clock		40	50	60	%

Notes to tables:

- (1) To implement the ClockLock and ClockBoost circuitry with the MAX+PLUS II software, designers must specify the input frequency. The Altera software tunes the PLL in the ClockLock and ClockBoost circuitry to this frequency. The f_{CLKDEV} parameter specifies how much the incoming clock can differ from the specified frequency during device operation. Simulation does not reflect this parameter.
- (2) Twenty-five thousand parts per million (PPM) equates to 2.5% of input clock period.
- (3) During device configuration, the ClockLock and ClockBoost circuitry is configured before the rest of the device. If the incoming clock is supplied during configuration, the ClockLock and ClockBoost circuitry locks during configuration because the t_{LOCK} value is less than the time required for configuration.
- (4) The t_{IITTER} specification is measured under long-term observation. The maximum value for t_{IITTER} is 200 ps if $t_{INCLKSTB}$ is lower than 50 ps.

I/O Configuration

This section discusses the peripheral component interconnect (PCI) pull-up clamping diode option, slew-rate control, open-drain output option, and MultiVolt I/O interface for FLEX 10KE devices. The PCI pull-up clamping diode, slew-rate control, and open-drain output options are controlled pin-by-pin via Altera software logic options. The MultiVolt I/O interface is controlled by connecting $V_{\rm CCIO}$ to a different voltage than $V_{\rm CCINT}.$ Its effect can be simulated in the Altera software via the **Global Project Device Options** dialog box (Assign menu).

The VCCINT pins must always be connected to a 2.5-V power supply. With a 2.5-V $V_{\rm CCINT}$ level, input voltages are compatible with 2.5-V, 3.3-V, and 5.0-V inputs. The VCCIO pins can be connected to either a 2.5-V or 3.3-V power supply, depending on the output requirements. When the VCCIO pins are connected to a 2.5-V power supply, the output levels are compatible with 2.5-V systems. When the VCCIO pins are connected to a 3.3-V power supply, the output high is at 3.3 V and is therefore compatible with 3.3-V or 5.0-V systems. Devices operating with $V_{\rm CCIO}$ levels higher than 3.0 V achieve a faster timing delay of t_{OD2} instead of t_{OD1} .

Table 14 summarizes FLEX 10KE MultiVolt I/O support.

Table 14. FLEX 10	Table 14. FLEX 10KE MultiVolt I/O Support									
V _{CCIO} (V)	In	out Signal	(V)	Out	put Signal	(V)				
	2.5 3.3 5.0 2.5 3.3 5.0									
2.5	✓	√ (1)	√ (1)	✓						
3.3	✓	✓	√ (1)	√ (2)	✓	✓				

Notes:

- The PCI clamping diode must be disabled to drive an input with voltages higher than V_{CCIO}.
- (2) When $V_{\rm CCIO}$ = 3.3 V, a FLEX 10KE device can drive a 2.5-V device that has 3.3-V tolerant inputs.

Open-drain output pins on FLEX 10KE devices (with a pull-up resistor to the 5.0-V supply) can drive 5.0-V CMOS input pins that require a $V_{\rm IH}$ of 3.5 V. When the open-drain pin is active, it will drive low. When the pin is inactive, the trace will be pulled up to 5.0 V by the resistor. The open-drain pin will only drive low or tri-state; it will never drive high. The rise time is dependent on the value of the pull-up resistor and load impedance. The $I_{\rm OL}$ current specification should be considered when selecting a pull-up resistor.

Power Sequencing & Hot-Socketing

Because FLEX 10KE devices can be used in a mixed-voltage environment, they have been designed specifically to tolerate any possible power-up sequence. The $V_{\rm CCIO}$ and $V_{\rm CCINT}$ power planes can be powered in any order.

Signals can be driven into FLEX 10KE devices before and during power up without damaging the device. Additionally, FLEX 10KE devices do not drive out during power up. Once operating conditions are reached, FLEX 10KE devices operate as specified by the user.

Table 17. 32-	Table 17. 32-Bit IDCODE for FLEX 10KE Devices Note (1)											
Device		IDCODE (32 Bits)										
	Version (4 Bits)	Part Number (16 Bits)	Manufacturer's Identity (11 Bits)	1 (1 Bit) (2)								
EPF10K30E	0001	0001 0000 0011 0000	00001101110	1								
EPF10K50E EPF10K50S	0001	0001 0000 0101 0000	00001101110	1								
EPF10K100E	0010	0000 0001 0000 0000	00001101110	1								
EPF10K130E	0001	0000 0001 0011 0000	00001101110	1								
EPF10K200E EPF10K200S	0001	0000 0010 0000 0000	00001101110	1								

Notes:

- (1) The most significant bit (MSB) is on the left.
- (2) The least significant bit (LSB) for all JTAG IDCODEs is 1.

FLEX 10KE devices include weak pull-up resistors on the JTAG pins.



For more information, see the following documents:

- Application Note 39 (IEEE Std. 1149.1 (JTAG) Boundary-Scan Testing in Altera Devices)
- BitBlaster Serial Download Cable Data Sheet
- ByteBlasterMV Parallel Port Download Cable Data Sheet
- Jam Programming & Test Language Specification

Driven

Figure 20. FLEX 10KE JTAG Waveforms TMS TDI t_{JPSU} TCK t_{JPZX} t _{JPXZ} $\mathbf{t}_{\mathsf{JPCO}}$ TDO t_{JSH} t_{JSSU} Signal to Be Captured t_{JSCO}t_{JSZX} t_{JSXZ} Signal to Be

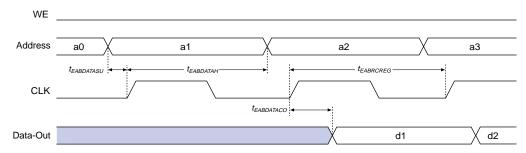
Figure 20 shows the timing requirements for the JTAG signals.

Table 18 shows the timing parameters and values for FLEX 10KE devices.

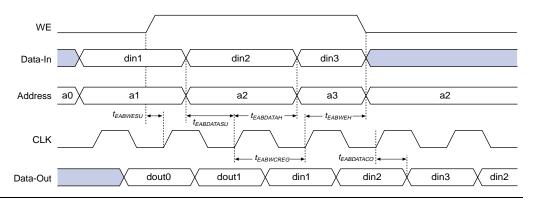
Table 1	8. FLEX 10KE JTAG Timing Parameters & Values			
Symbol	Parameter	Min	Max	Unit
t _{JCP}	TCK clock period	100		ns
t _{JCH}	TCK clock high time	50		ns
t _{JCL}	TCK clock low time	50		ns
t _{JPSU}	JTAG port setup time	20		ns
t _{JPH}	JTAG port hold time	45		ns
t _{JPCO}	JTAG port clock to output		25	ns
t _{JPZX}	JTAG port high impedance to valid output		25	ns
t _{JPXZ}	JTAG port valid output to high impedance		25	ns
t _{JSSU}	Capture register setup time	20		ns
t _{JSH}	Capture register hold time	45		ns
t _{JSCO}	Update register clock to output		35	ns
t _{JSZX}	Update register high impedance to valid output		35	ns
t _{JSXZ}	Update register valid output to high impedance		35	ns

Figure 30. EAB Synchronous Timing Waveforms

EAB Synchronous Read



EAB Synchronous Write (EAB Output Registers Used)



Tables 31 through 37 show EPF10K30E device internal and external timing parameters.

Table 31. EPF10	K30E Device	LE Timing N	1icroparame	ters (Part 1	of 2) No	ote (1)	
Symbol	-1 Spec	-1 Speed Grade		-2 Speed Grade		d Grade	Unit
	Min	Max	Min	Max	Min	Max	
t_{LUT}		0.7		0.8		1.1	ns
t _{CLUT}		0.5		0.6		0.8	ns
t _{RLUT}		0.6		0.7		1.0	ns
t _{PACKED}		0.3		0.4		0.5	ns
t_{EN}		0.6		0.8		1.0	ns
t _{CICO}		0.1		0.1		0.2	ns
t _{CGEN}		0.4		0.5		0.7	ns

Table 38. EPF10K	50E Device	LE Timing M	licroparame	ters (Part 2	of 2) No	te (1)	
Symbol	-1 Spee	d Grade	-2 Spee	d Grade	-3 Spee	d Grade	Unit
	Min	Max	Min	Max	Min	Max	
t _H	0.9		1.0		1.4		ns
t _{PRE}		0.5		0.6		0.8	ns
t _{CLR}		0.5		0.6		0.8	ns
t _{CH}	2.0		2.5		3.0		ns
t_{CL}	2.0		2.5		3.0		ns

Symbol	-1 Spee	d Grade	-2 Spee	ed Grade	-3 Spee	ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t_{IOD}		2.2		2.4		3.3	ns
t _{IOC}		0.3		0.3		0.5	ns
t _{IOCO}		1.0		1.0		1.4	ns
t_{IOCOMB}		0.0		0.0		0.2	ns
t _{IOSU}	1.0		1.2		1.7		ns
t_{IOH}	0.3		0.3		0.5		ns
t_{IOCLR}		0.9		1.0		1.4	ns
t_{OD1}		0.8		0.9		1.2	ns
t_{OD2}		0.3		0.4		0.7	ns
t_{OD3}		3.0		3.5		3.5	ns
t_{XZ}		1.4		1.7		2.3	ns
t_{ZX1}		1.4		1.7		2.3	ns
t _{ZX2}		0.9		1.2		1.8	ns
t _{ZX3}		3.6		4.3		4.6	ns
t _{INREG}		4.9		5.8		7.8	ns
t _{IOFD}		2.8		3.3		4.5	ns
t _{INCOMB}		2.8		3.3		4.5	ns

Symbol	-1 Spee	d Grade	-2 Spee	-2 Speed Grade		ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t _{EABDATA1}		1.5		2.0		2.6	ns
t _{EABDATA1}		0.0		0.0		0.0	ns
t _{EABWE1}		1.5		2.0		2.6	ns
t _{EABWE2}		0.3		0.4		0.5	ns
t _{EABRE1}		0.3		0.4		0.5	ns
t _{EABRE2}		0.0		0.0		0.0	ns
t _{EABCLK}		0.0		0.0		0.0	ns
t _{EABCO}		0.3		0.4		0.5	ns
t _{EABBYPASS}		0.1		0.1		0.2	ns
t _{EABSU}	0.8		1.0		1.4		ns
t _{EABH}	0.1		0.1		0.2		ns
t _{EABCLR}	0.3		0.4		0.5		ns
t_{AA}		4.0		5.1		6.6	ns
t_{WP}	2.7		3.5		4.7		ns
t_{RP}	1.0		1.3		1.7		ns
t _{WDSU}	1.0		1.3		1.7		ns
t _{WDH}	0.2		0.2		0.3		ns
t _{WASU}	1.6		2.1		2.8		ns
t _{WAH}	1.6		2.1		2.8		ns
t _{RASU}	3.0		3.9		5.2		ns
t _{RAH}	0.1		0.1		0.2		ns
t _{WO}		1.5		2.0		2.6	ns
t _{DD}		1.5		2.0		2.6	ns
t _{EABOUT}		0.2		0.3		0.3	ns
t _{EABCH}	1.5		2.0		2.5		ns
t _{EABCL}	2.7		3.5		4.7		ns

Table 48. EPF10K100E Device EAB Internal Timing Macroparameters (Part 1 of 2) Note (1)							
Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t _{EABAA}		5.9		7.6		9.9	ns
t _{EABRCOMB}	5.9		7.6		9.9		ns
t _{EABRCREG}	5.1		6.5		8.5		ns
t _{EABWP}	2.7		3.5		4.7		ns

Table 69. EPF10	K50S Device	EAB Interna	l Timing Ma	croparamet	ers Note	(1)	
Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t _{EABAA}		3.7		5.2		7.0	ns
t _{EABRCCOMB}	3.7		5.2		7.0		ns
t _{EABRCREG}	3.5		4.9		6.6		ns
t _{EABWP}	2.0		2.8		3.8		ns
t _{EABWCCOMB}	4.5		6.3		8.6		ns
t _{EABWCREG}	5.6		7.8		10.6		ns
t _{EABDD}		3.8		5.3		7.2	ns
t _{EABDATACO}		0.8		1.1		1.5	ns
t _{EABDATASU}	1.1		1.6		2.1		ns
t _{EABDATAH}	0.0		0.0		0.0		ns
t _{EABWESU}	0.7		1.0		1.3		ns
t _{EABWEH}	0.4		0.6		0.8		ns
t _{EABWDSU}	1.2		1.7		2.2		ns
t _{EABWDH}	0.0		0.0		0.0		ns
t _{EABWASU}	1.6		2.3		3.0		ns
t _{EABWAH}	0.9		1.2		1.8		ns
t _{EABWO}		3.1		4.3		5.9	ns

Table 70. EPF10K50S Device Interconnect Timing Microparameters Note (1)							
Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t _{DIN2IOE}		3.1		3.7		4.6	ns
t _{DIN2LE}		1.7		2.1		2.7	ns
t _{DIN2DATA}		2.7		3.1		5.1	ns
t _{DCLK2IOE}		1.6		1.9		2.6	ns
t _{DCLK2LE}		1.7		2.1		2.7	ns
t _{SAMELAB}		0.1		0.1		0.2	ns
t _{SAMEROW}		1.5		1.7		2.4	ns
t _{SAME} COLUMN		1.0		1.3		2.1	ns
t _{DIFFROW}		2.5		3.0		4.5	ns
t _{TWOROWS}		4.0		4.7		6.9	ns
t _{LEPERIPH}		2.6		2.9		3.4	ns
t _{LABCARRY}		0.1		0.2		0.2	ns
t _{LABCASC}		0.8		1.0		1.3	ns

Power Consumption

The supply power (P) for FLEX 10KE devices can be calculated with the following equation:

$$P = P_{INT} + P_{IO} = (I_{CCSTANDBY} + I_{CCACTIVE}) \times V_{CC} + P_{IO}$$

The $I_{CCACTIVE}$ value depends on the switching frequency and the application logic. This value is calculated based on the amount of current that each LE typically consumes. The P_{IO} value, which depends on the device output load characteristics and switching frequency, can be calculated using the guidelines given in *Application Note 74 (Evaluating Power for Altera Devices)*.

Compared to the rest of the device, the embedded array consumes a negligible amount of power. Therefore, the embedded array can be ignored when calculating supply current.

The I_{CCACTIVE} value can be calculated with the following equation:

$$I_{CCACTIVE} = K \times f_{\boldsymbol{MAX}} \times N \times \boldsymbol{tog_{LC}} \times \frac{\mu A}{MHz \times LE}$$

Where:

f_{MAX} = Maximum operating frequency in MHz N = Total number of LEs used in the device

tog_{LC} = Average percent of LEs toggling at each clock

(typically 12.5%)

K = Constant

Table 80 provides the constant (K) values for FLEX 10KE devices.

Table 80. FLEX 10KE K Constant Values					
Device	K Value				
EPF10K30E	4.5				
EPF10K50E	4.8				
EPF10K50S	4.5				
EPF10K100E	4.5				
EPF10K130E	4.6				
EPF10K200E	4.8				
EPF10K200S	4.6				

This calculation provides an I_{CC} estimate based on typical conditions with no output load. The actual I_{CC} should be verified during operation because this measurement is sensitive to the actual pattern in the device and the environmental operating conditions.

During initialization, which occurs immediately after configuration, the device resets registers, enables I/O pins, and begins to operate as a logic device. The I/O pins are tri-stated during power-up, and before and during configuration. Together, the configuration and initialization processes are called *command mode*; normal device operation is called *user mode*.

SRAM configuration elements allow FLEX 10KE devices to be reconfigured in-circuit by loading new configuration data into the device. Real-time reconfiguration is performed by forcing the device into command mode with a device pin, loading different configuration data, reinitializing the device, and resuming user-mode operation. The entire reconfiguration process requires less than 85 ms and can be used to reconfigure an entire system dynamically. In-field upgrades can be performed by distributing new configuration files.

Before and during configuration, all I/O pins (except dedicated inputs, clock, or configuration pins) are pulled high by a weak pull-up resistor.

Programming Files

Despite being function- and pin-compatible, FLEX 10KE devices are not programming- or configuration file-compatible with FLEX 10K or FLEX 10KA devices. A design therefore must be recompiled before it is transferred from a FLEX 10K or FLEX 10KA device to an equivalent FLEX 10KE device. This recompilation should be performed both to create a new programming or configuration file and to check design timing in FLEX 10KE devices, which has different timing characteristics than FLEX 10K or FLEX 10KA devices.

FLEX 10KE devices are generally pin-compatible with equivalent FLEX 10KA devices. In some cases, FLEX 10KE devices have fewer I/O pins than the equivalent FLEX 10KA devices. Table 81 shows which FLEX 10KE devices have fewer I/O pins than equivalent FLEX 10KA devices. However, power, ground, JTAG, and configuration pins are the same on FLEX 10KA and FLEX 10KE devices, enabling migration from a FLEX 10KA design to a FLEX 10KE design.